A QUANTUM CHEMICAL STUDY OF EFFECTS OF SILYL SUBSTITUENTS IN PHENYL- AND BENZYLSILANES*

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Charge-transfer spectra of series of substituted phenyl- and benzylsilanes and some carbon analogues were measured with tetracyanoethylene as the acceptor in dichloromethane solutions in the 15000–35000 cm⁻¹ region. The obtained results can be interpreted by interaction with Σ_{π}^* orbitals of (CH₂—Si) or (Si—X) bonds, without assuming the participation of silicon *d* orbitals. These conclusions are supported by the results of quantum chemical calculations performed for phenylsilanes and for corresponding carbon analogues by a simple HMO method. The wavenumbers of charge-transfer bands correlate well with calculated values of the highest occupied molecular orbital energies (HOMO).

The results obtained in our laboratory^{1,2}, and previously also in other laboratories^{3,4}, show that to explain electron acceptor character of silicon, it is not necessary to invoke the participation of its 3*d* orbitals through the so-called $(p \rightarrow d)_{\pi}$ bonds. The same conclusions can be reached by assuming the interaction with low-lying antibonding orbitals, $\sigma^*(Si_{--}X)$ or $\sigma^*(CH_2-Si)$, which becomes increasingly important as the electronegativity of X increases. To prove the correctness of these assumptions on a more sophisticated level than orbital diagrams, it was of interest to perform quantum chemical calculations with a model of a silyl group which would enable these effects to be at least qualitatively included. These requirements were not met in the earlier proposed model of the silicon atom for HMO calculations⁵. This latter model, which assumes that only one unoccupied silicon orbital is engaged in conjugation, does not render it possible to explain the donor properties of trimethylsilyl group which were established by *e.g.* photoelectron spectroscopy (I.P. of benzene = 9.24 eV, I.P. of phenyltrimethylsilane = 8.94 eV) (ref.⁶).

A model of the MX_3 group was therefore suggested which assumes that atom M and atom X contributes to conjugation, each by one orbital occupied by one electron. This, in dependence on the values of corresponding coulombic and resonance integrals, makes it possible to obtain both acceptor and donor properties of the MX_3

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group. The calculations were performed for phenylsilanes and corresponding carbon compounds with substituents X = F, Cl, H, and CH₃.

EXPERIMENTAL

Model compounds. All the compounds under study, except those commercially available, were prepared by reported procedures. In Table I are therefore recorded only their boiling points and references to the original literature. The purity of the compounds was checked by gas chromatography. The compounds all contained less than 1% of impurities.

Benzene (UV spectrograde, Lachema, Brno) was dried by refluxing it with sodium and then rectified. The fraction collected at $80-80.5^{\circ}$ C was stored in a small flask over Nalsit 4 A molecular sieve. Toluene (UV spectrograde, Lachema, Brno) was dried and purified similarly as benzene. A fraction boiling at 110–111^oC was stored over Nalsit 4 A molecular sieve. Ethylbenzene (*purris.*, Fluka), t-butylbenzene (*purris.*, Fluka), benzotrifluoride (*purum.*, Fluka), benzotrichloride (*purum.*, Fluka), and tetracyanoethylene (*purum.*, Fluka), all were used without further purification. Dichloromethane (analytical purity grade, Lachema, Brno) was purified by the method described earlier¹.

TABLE I

Characteristic Constants of Studied Compounds and Wavenumbers of the Maxima of Their Charge-Transfer Bands with Tetracyanoethylene in Dichloromethane

Compounds	B.p., °C/Torr	B.p., °C/Torr (ref.)	v, cm ⁻¹	v, cm ⁻¹ a
Benzene (1)	80-80.5	80·1 ⁸	$26\ 000\pm100$	26 050
Toluene (2)	110-111	110.6^{8}	$24\ 600\pm 200$	24 650
t-Butylbenzene (3)	167-169	169·1 ⁸	$24~000\pm200$	24 000
Benzotrichloride (4)	90-91/15	214 ⁸	$28\ 700\pm\ 500$	_
Benzotrifluoride (5)	100-103	102·4 ⁸	$30\;500\pm\;500$	_
Phenyltrimethylsilane (6)	168-170	170.6^{9}	$24~500\pm100$	24 650
Phenylsilane (7)	120-121	120 ¹⁰	$25\ 700 \pm 200$	26 000
Phenyltriethoxysilane (8)		$108.5/3^{11,12}$	$26\ 200\ \pm\ 200$	_
Phenyltrichlorosilane (9)	197-200	$201 \cdot 1^{13}$	$29\;300\pm300$	_
Phenyltrifluorosilane (10)	100 - 101	$101 \cdot 8^{14}$	$30\ 600\pm\ 500$	
p-Tolylsilane (11)	147 - 148	147—148 ¹⁶	$23\ 700\pm 200$	—
p-Tolyltrimethylsilane (12)	188-191	190—191 ¹⁵	$23\;500\pm200$	_
Ethylbenzene (13)	134-136	136·1 ⁸	$24\ 000\ \pm\ 100$	24 200
Benzyltrimethylsilane (14)	189-191	$191 - 192^{17}$	$20\ 400\ \pm\ 100^{b}$	20 550 ^b
			$24\ 200\pm100$	24 050
Benzylsilane (15)	149-150	150.3^{18}	$24~500\pm200$	
Benzyltrichlorosilane (16)	212-215	140—142/100 ¹⁹	$25~300\pm~300$	25 300
Benzyltrifluorosilane (17)	134-135	$134 - 135^{14}$	$25\ 800\ \pm\ 300$	25 700
Benzyltriethoxysilane (18)	245-250	170—175/70 ¹⁹	$24\ 100\pm\ 300$	-

^a Data reported by Bock⁷; ^b two separate bands.

Charge-transfer spectra of all the compounds studied were measured with the use of tetracyanoethylene as an acceptor in dichloromethane solution on a double-beam SiO_2 -prism Specord, Zeiss, spectrophotometer (Jena, GDR) in the 15000-35000 cm⁻¹ region under the conditions reported in a previous work¹. Experimental wavenumbers of charge-transfer band maxima are recorded in Table I. For purposes of comparison, also the data reported by Bock⁷ are included.

RESULTS AND DISCUSSION

The model of the MX₃ group suggested in this work is based on Bishop's²¹ semiempirical model of hyperconjugation, but it is of course modified to HMO level. The orbitals of σ (M—X) bonds can be, due to their symmetry (C_{3v}), combined into group orbitals, two of which are of suitable symmetry for interaction with the phenyl π system. When going from these equivalent orbitals to atomic orbitals, one obtains

$$\begin{split} \Sigma_{\pi}^{\rm M} &= \frac{1}{\sqrt{6}} \left(2 \phi_{\rm M}^1 - \phi_{\rm M}^2 - \phi_{\rm M}^3 \right) \\ \Sigma_{\pi}^{\rm X} &= \frac{1}{\sqrt{6}} \left(2 \phi_{\rm X}^1 - \phi_{\rm X}^2 - \phi_{\rm X}^3 \right). \end{split}$$

These orbitals then serve as the basis for our model. Each orbital is occupied by one electron, and because of identical symmetry they may interact. This manifests itself in the formation of the "bonding" combination $\Sigma_{\pi} = (\Sigma_{\pi}^{M} + \Sigma_{\pi}^{X})$, occupied by two electrons, and of the unoccupied "antibonding" combination $\Sigma_{\pi}^{*} = \Sigma_{\pi}^{M} - \Sigma_{\pi}^{X}$. The model can be schematically depicted in the following way:



The values of coulombic integrals α_m^M a α_x^X are taken as being roughly proportional to corresponding orbital ionization potentials^{21,22} and, along with the values of corresponding resonance integrals, are listed in Table II.

Bock⁷ reported that the charge-transfer band of substituted phenyl- and benzylsilanes is formed by two overlapping bands which originate from the degenerate e_{1g} orbital of benzene. The observed maximum of the charge-transfer band does not correspond to the energy of the highest occupied molecular orbital. However, with regard to the fact that Bock⁷ did not succeed in separating the above two bands and that experimental values of v_{CT} correlate with available values of first ionization potentials^{6,23}, we used the wavenumber of the maxima of the charge-transfer band also in correlations with calculated energies of HOMO. The suitability of the parameters was further verified with a series of substituted silafluorenes²⁴, where difficulties with degeneration do not exist. The correlation of the wavenumbers of chargetransfer bands with calculated values of ϵ (HOMO) for substituted phenylsilanes and some carbon analogues are graphically represented in Fig. 1.

The calculations correctly reproduce the trend in the values of v_{CT} which decrease in the order SiF₃ > SiCl₃ > SiH₃ > Si(CH₃)₃ and in the order CF₃ > CCl₃ > > CH₃ > C(CH₃)₃. It is seen that there is no qualitative difference between silicon and carbon. The greater deviations of the values of v_{CT} from the regression line found for the chloro-substituted derivatives can be ascribed to steric effects which prevent the molecule of the acceptor (TCNE) from achieving in the complex the equilibrium geometry identical with the geometry of the other cases. This agrees with the fact that the greater deviations were observed in the carbon series than in the silicon one. Calculations also correctly reproduce the symmetry and form of the highest occupied orbital (B_1 , $\pi - \Sigma_n$). The lowest free molecular orbital (LFMO) is in all cases nearly pure Σ_n^* orbital. The values of orbital energies of HOMO and LFMO, and the values of electron densities on atom X are listed in Table III.



The order of acceptor strength of group MX_3 is the same in both series (M = C, Si) $F > Cl > (C_2H_5O) > H > CH_3$, parallels the electronegativity of X, and thus also the order of $\sigma^*(M-X)$. It is necessary to stress that on the basis of symmetry alone it is not possible to decide whether in the series of substituted silanes the interaction of the π -system occurs with a d_{yz} orbital or with a Σ_{π}^* orbital. Arguments of the perturbation theory¹, together with the fact that the same trend is observed also in the analogous series of carbon compounds, support the assumption about the participation of the Σ_{π}^* orbital. The same order of acceptor strength is always observed when the π system interacts directly with (M-X) bonds (phenylsilanes, silafluorenes²⁴). A somewhat different order is found, however, in the series of benzyl- and allylsilanes¹: $X = F > Cl > H > C_2H_3O > CH_3$. This difference can be understood when one considers that in this case the π system is interacting with the σ orbital of the (CH_2-Si) bond. This orbital, because the ethoxy group is not a monoatomic substituent, may also be influenced by other factors than by the electronegativity of oxygen, as shown *e.g.* by the following scheme:



Another complication stems from the lack of knowledge of the steric arrangement of the three ethoxy groups on the silicon atom, since the above-mentioned interaction requires syn-clinal arrangement of (CH_2-Si) and $(O-CH_2)$ bonds.

The suitability of the discussed hyperconjugation model can be further verified, e.g. by examining whether it is able to describe, at least qualitatively, the order of acidity of some hydrocarbons of similar structure containing (CH₂) or (CH₃) group. A rough estimate is provided by comparison of the electron densities on hydrogen atoms of the CH₂(CH₃) group: cyclopentadiene (0.898) < indene (0.911) < < fluorene (0.926) < toluene (1.007). In the series of silicon derivatives $q_{\rm H} > 1$, which corresponds to the generally accepted polarity of the Si³⁴—H³ – bond (Table III). A theoretically more correct measure of basicity is the difference in total π -elec-

M	(α _M)	х	α _X	β_{C-X}	β_{M-C}	β_{M-C}
Si	(-0.3)	F	-4.0	-2.0	-2.0	0.8
	• •	Cl	-2.5	-1.7	1.7	-0.8
		н	-1.3	-1.2	-1.2	-0.8
		CH ₃	-1.0	1.0	-1.0	0.8
С	(-1.0)	F	4.0	-2.0	-2.5	1·0
		Cl	-2.5	-1.7	-2.0	1·0
		н	-1.3	-1.2	-1.5	1· 0
		CH ₃	-1.0	-1.0	-1.5	-1.0

TABLE II Values of Empirical Parameters in Hyperconjugation Model of MX₃ Group (in β Units)



FIG. 1

Dependence of Wavenumbers of Maxima of Charge-Transfer Bands of Studied Compounds on Calculated Values of HOMO Energy

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TABLE III

Calculated Quantum Chemical Quantities for Some Compounds Studied

 ε (HOMO) the energy of the highest occupied molecular orbital, ε (LFMO) the energy of the lowest free molecular orbital, q_X the electron density on atom X.

Compound	ε (HOMO (β) ν	(LFMO) (β)) q _X	
2	-0.654	0.356	1.0069	
3	0.639	0.200	0.9199	
4	-0.662	0.380	1.2361	
5	0.694	0.417	1.4136	
6	-0.600	0.408	1.2225	
7	-0.614	0.200	1.2636	
9	0.645	0.619	1.4129	
10	0.680	0.570	1.5659	
11	-0.594^{a}	_		3
12	-0·597 ^a	-		

^{*a*} Values calculated by means of first-order perturbation theory from wave functions for phenylsilane (7) and phenyltrimethylsilane (6) according to the relation $\Delta e_i = c_{1u}^2 \Delta \alpha_u$; $\Delta x_u \approx 0.1\beta$.

tron energies between parent hydrocarbons and their anions. Their order also parallels the order of experimentally found acidity of hydrocarbons²⁵: $(\Delta W_{\pi}(\beta))$ for cyclopentadiene 5.18, indene 5.21, and fluorene 5.26.

REFERENCES

- 1. Ponec R., Chvalovský V.: This Journal 38, 3845 (1973).
- Ponec R., Chvalovský V., Černyšev E. A., Komarenkova N. G., Baškirova S. A.: This Journal 39, 1177 (1974).
- 3. Pitt C. G.: Chem. Commun. 1971, 816.
- 4. Schweig A., Haase L.: Tetrahedron 29, 1637 (1973).
- 5. Allred L. A., Curtis M. D.: J. Am. Chem. Soc. 87, 2554 (1965).
- Turner D. W., Baker C., Baker D., Brundle C. R.: Molecular Photoelectron Spectroscopy. Wiley, New York 1970.
- 7. Bock H., Alt H.: J. Am. Chem. Soc. 92, 1569 (1970).
- 8. Handbook of Chemistry and Physics (Ch. D. Hodgman, Ed.). Chemical Rubber Publishing Co., Cleveland 1957.
- 9. Freiser H., Eagle M. W., Speier L. J.: J. Am. Chem. Soc. 75, 2821 (1953).
- Finholt A. E., Bond E. A. jr, Wilzbach K. E., Schlezinger H. J.: J. Am. Chem. Soc. 69, 2692 (1947).
- 11. Nebergall W. H.: J. Am. Chem. Soc. 72, 4702 (1950).
- 12. Kalinin N. M.: Dokl. Akad. Nauk SSSR 24, 365 (1940).
- 13. Voronkov M. G., Dolgov B. N.: Ž. Obšč. Chim. 24, 1082 (1954).
- Ponomarenko V. A., Snegova A. D., Egorov P. J.: Izv. Akad. Nauk SSSR, Ser. Chim. 1960, 244.

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- Topčiev V. A., Pančenkov G. M., Nametkin N. S., Gundyrev N. S., Gu-Chan-Li: Trudy Konf. Chim. Prakt. Primenenije Kremneorganičeskich Sojedinenij 3, 80 (1958); Leningrad, 1958.
- 16. Hughes M. B.: Dissertation Abstr. 19, 1921 (1959).
- 17. Petrov D. A., Černyšev E. A., Dolgaja M. E.: Ž. Obšč. Chim. 25, 2469 (1955).
- 18. Anderson H. H., Grebe L. R.: J. Org. Chem. 26, 2006 (1961).
- 19. Martin G., Kipping E. S.: J. Chem. Soc. 95, 302 (1909).
- 20. Clusius K., Haimerl H.: Z. Physik. Chem. (Leipzig) A 51, 347 (1942).
- 21. Bishop D. M., Ito H .: Theor. Chim. Acta 16, 377 (1970).
- 22. Jaffe H. H., Hinze J.: Am. Chem. Soc. 84, 540 (1962).
- 23. Allan R., McLean N.: Can. J. Chem. 51, 2089 (1973).
- 24. Ponec R. Chvalovský V., Černyšev E. A., Krasnova T. L.: This Journal, in press.
- Streitwiesser A. jr, Hammons J. H. in the book: Progress in Physical Organic Chemistry (S. G. Cohen, A. Streitwiesser jr, R. W. Taft, Eds), Vol. 3, p. 41. Wiley, New York 1965.

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